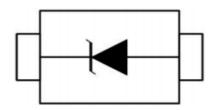
Single Line Uni-directional ESD and Transient Voltage Protection

SD07A0D32G1 SOD323



Pinout and Functional Block Diagram



Applications

- Power lines
- Microprocessor based equipment
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops, and Servers
- Cell Phone Handsets and Accessories
- Portable Instrumentation
- Peripherals

Description

The SD07A0D32G1 TVS diode is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebooks, and PDA's. It offers superior electrical characteristics such as low clamping voltage, low leakage current and high surge capability. It is designed to protect sensitive electronic components which are connected to power lines, from over-stress caused by ESD (Electrostatic Discharge), EFT (Electrical Fast Transients) and Lightning.

The SD07A0D32G1 is in a SOD-323 package and will protect one single line for unidirectional. It may be used to provide ESD protection up to \pm 30 kV (Contact and air discharge) according to IEC61000-4-2 , and used to protect USB voltage bus pin (8 / 20 μ s) according to IEC61000-4-5.

Features

- IEC61000-4-2 (ESD) ± 30 kV (Air), ± 30 kV (Contact)
- Peak Power Dissipation: 2625 W@8 / 20 μs
- Low Clamping Voltage
- Low Leakage Current
- Solid-state Silicon-avalanche Technology
- High Temperature to Reflow Soldering Guaranteed: 260 °C / 10 sec
- MSL1
- Flammability Rating: UL 94 V-0
- Halogen Free and RoHS Compliant

Order Information

Туре	Package	Marking Code	Delivery Form	Delivery Quantity
SD07A0D32G1	SOD323	H7	7" T&R	3000 PCS

Limiting Values

(T_A = 25 °C, unless otherwise specified)

Symbol	Parameter	Conditions		Max	Unit
		IEC 61000-4-2; Contact Discharge	-	30	kV
V _{ESD}	Electrostatic Discharge Voltage	IEC 61000-4-2; Air Discharge	-	30	kV
P _{PP}	Peak Pulse Power (8 / 20 μs)	Power (8 / 20 µs) -		2625	W
T _A	Operating Temperature Range	-		125	°C
T _{stg}	Storage Temperature Range	-	-55	150	°C

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Electrical Characteristics

(T_A = 25 °C, unless otherwise specified)

Symbol	Parameter	Conditions	Min	Тур.	Max	Unit
V _{RWM}	Reverse Working Voltage	-	-	-	7.0	V
V_{BR}	Breakdown Voltage	I _T = 1 mA	7.5	8.0	9.0	V
I _R	Reverse Leakage Current	V _{RWM} = 7 V	-	_	1	μA
I _{PP}	Peak Pulse Current	t _P =8 / 20 μs	-	-	105	Α
V _{C1}	Clamping Voltage 1	I _{PP} = 70 A, t _P =8 / 20 μs	-	17	19	V
V _{C2}	Clamping Voltage 2	I _{PP} = 105 A, t _P =8 / 20 μs	-	20	25	V
Сл	Junction Capacitance	V _R =0 V, f = 1 MHz	-	600	700	pF



ESD Protection Diodes Single Line Uni-directional ESD and Transient Voltage Protection

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Performance Curve for Reference

(T_A=25 °C unless otherwise noted)

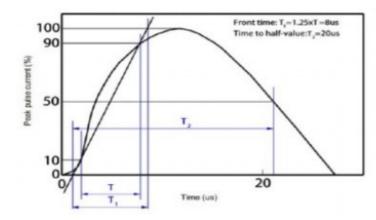


FIGURE 1 8 / 20 µs Waveform Per IEC61000-4-5

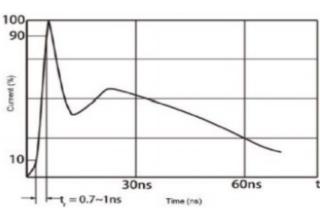


FIGURE 2 Contact Discharge Current Waveform Per IEC 61000-4-2

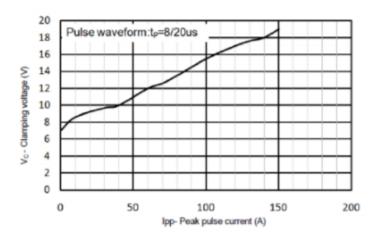


FIGURE 3 Clamping Voltage VS. Peak Pulse Current

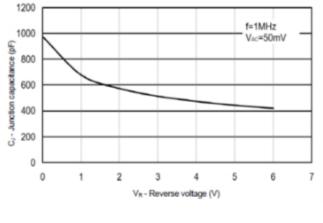
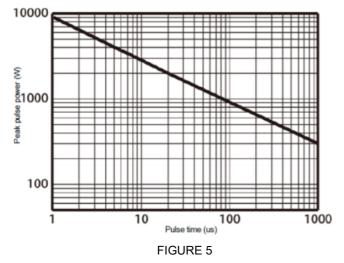
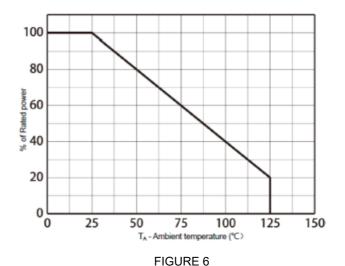


FIGURE 4 Capacitance VS. Reverse Voltage



Non-Repetitive Peak Pulse Power VS. Pulse Time



Power Derating VS. Ambient Temperature

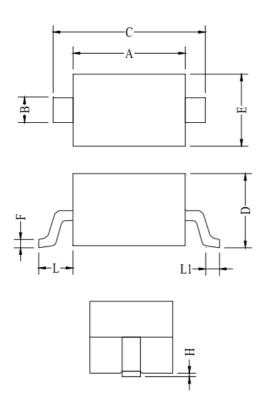


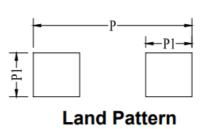


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Package Dimensions - SOD323



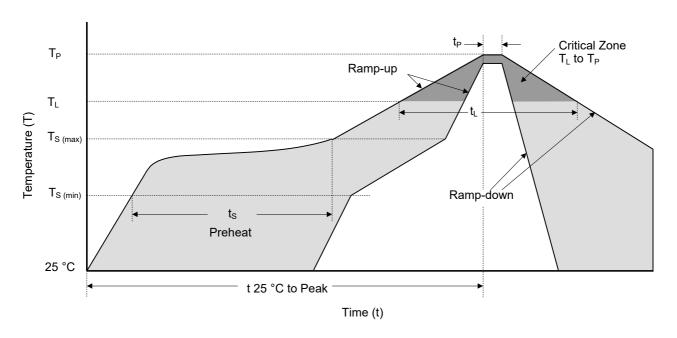


Symbol	Millimeters		Inches		
Syllibol	Min.	Max.	Min.	Max.	
Α	1.60	1.80	0.063	0.071	
В	0.25	0.40	0.010	0.016	
С	2.30	2.80	0.091	0.110	
D	0.80	1.10	0.031	0.043	
E	1.20	1.40	0.047	0.055	
F	0.08	0.18	0.003	0.007	
L	0.475 Ref.		0.019 Ref.		
L1	0.25	0.40	0.010	0.016	
Н	0.00	0.14	0.000	0.006	
Р	3.00		0.118		
P1	0.80		C	0.031	

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Soldering Parameters



Reflowing Condition

Reflow Solderin	Lead-Free Assembly			
	Temperature Min (T _{S (min)})	150 °C		
Pre-heat	Temperature Max (T _{S (max)})	200 °C		
	Time (min to max) (t₅)	60 ~ 120 seconds		
Average Ramp Up Rate (Li	Average Ramp Up Rate (Liquidus Temp (TL) to Peak			
T _s (max) to T _L	Ramp-up Rate	3 °C / second max.		
	Temperature (T _L) (Liquidus)	217 °C		
Reflow	Time (min to max) (t _L)	60 ~ 150 seconds		
Peak Tempe	260 ^{+0/-5} °C			
Time of within 5 °C of Actu	20 ~ 40 seconds			
Ramp-do	6 °C / second max.			
Time from 25 °C to Peak Temperature		8 Minutes max.		
Do Not Exceed		260 °C		

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Usage

- 1. TVS must be operated in the specified ambient temp.
- 2. Do not clean the TVS with strong polar solvent such as ketone, esters, benzene and halogenated hydrocarbon, to avoid damaging the encapsulating layer.
- 3. Please do not apply severe vibration, shock or pressure to TVS, to avoid element cracking.

Replacement

- 1. If TVS is visually damaged, please replace it.
- 2. TVS is a non-repairable product. For safety sake, please use equivalent TVS for replacement.

Storage

- 1. Storage Temp. Range: (-55 to 150) °C.
- 2. Do not store the TVS at the high temp., high humidity or corrosive gas environment, to avoid influencing the solder- ability of the lead wires. The product shall be used up within 1 year after receiving the goods.

Environmental Conditions

- 1. TVS should not be exposed to the open air, nor direct sunshine.
- 2. TVS should avoid rain, water vapor or other condition of high temp. and high humidity.
- 3. TVS should avoid sand dust, salt mist, or other harmful gases.

Max. Typical Capacitance of TVS

1. The typical capacitance of TVS is listed in the specifications. Designers may refer to it when designing TVS in High frequency circuit.

Installation Mechanical Stress

- 1. Do not knock TVS when installing, to avoid mechanical damage.
- 2. Please do not apply severe vibration, shock or pressure to TVS, to avoid surface resin or element cracking.